DISCRETE SEMICONDUCTORS

DATA SHEET

PZ1418B15U
NPN microwave power transistor

Product specification
Supersedes data of November 1994

1997 Feb 19

Philips Semiconductors

PHILIPS

NPN microwave power transistor PZ1418B15U

FEATURES

- Interdigitated structure provides high emitter efficiency
- Diffused emitter ballasting resistors providing excellent current sharing and withstanding a high VSWR
- Gold metallization realizes very stable characteristics and excellent lifetime
- Multicell geometry gives good balance of dissipated power and low thermal resistance
- Internal input and output prematching ensures good stability and easy broadband use.

APPLICATIONS

- Common base class-B wideband amplifiers under CW conditions in military and professional applications, and to drive the type PZ1418B30U.

DESCRIPTION

NPN silicon planar epitaxial microwave power transistor in a SOT443A metal ceramic flange package with the base connected to the flange.

PINNING - SOT443A

PIN	DESCRIPTION
1	collector
2	emitter
3	base connected to flange

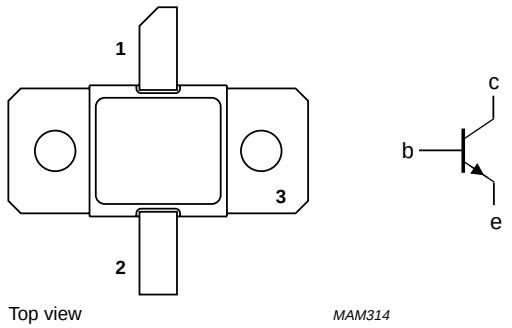


Fig.1 Simplified outline and symbol.

QUICK REFERENCE DATA

RF performance up to T_{mb} = 25 °C in a common base class-B wideband amplifier.

MODE OF OPERATION	f (GHz)	V_{CC} (V)	P_L (W)	G_p (dB)	η_C (%)	Z_i; Z_L (Ω)
Class-B	1.4 to 1.8	28	≥12.5	≥7	≥38	see Figs 6 and 7

WARNING
Product and environmental safety - toxic materials
This product contains beryllium oxide. The product is entirely safe provided that the BeO slab is not damaged. All persons who handle, use or dispose of this product should be aware of its nature and of the necessary safety precautions. After use, dispose of as chemical or special waste according to the regulations applying at the location of the user. It must never be thrown out with the general or domestic waste.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter	–	40	V
V_{CEO}	collector-emitter voltage	open base	–	15	V
V_{CES}	collector-emitter voltage	R_{BE} = 0 Ω	–	35	V
V_{EBO}	emitter-base voltage	open collector	–	3	V
I_C	collector current (DC)		–	2	A
P_{tot}	total power dissipation	$T_{mb} \leq 75$ °C	–	27	W
T_{stg}	storage temperature		–65	+200	°C
T_j	operating junction temperature		–	200	°C
T_{sld}	soldering temperature		–	235	°C

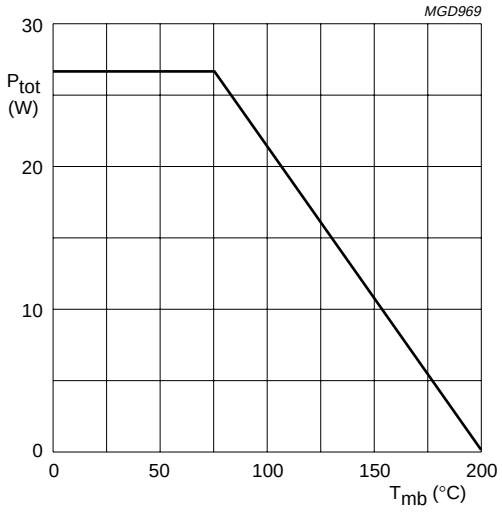


Fig.2 Power derating curve.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
$R_{th\ j\text{-}mb}$	thermal resistance from junction to mounting-base	T_j = 75 °C	4	K/W
$R_{th\ mb\text{-}h}$	thermal resistance from mounting-base to heatsink	T_j = 75 °C; note 1	0.2	K/W

Note

1. See "*Mounting recommendations in the General part of handbook SC15*".

CHARACTERISTICS

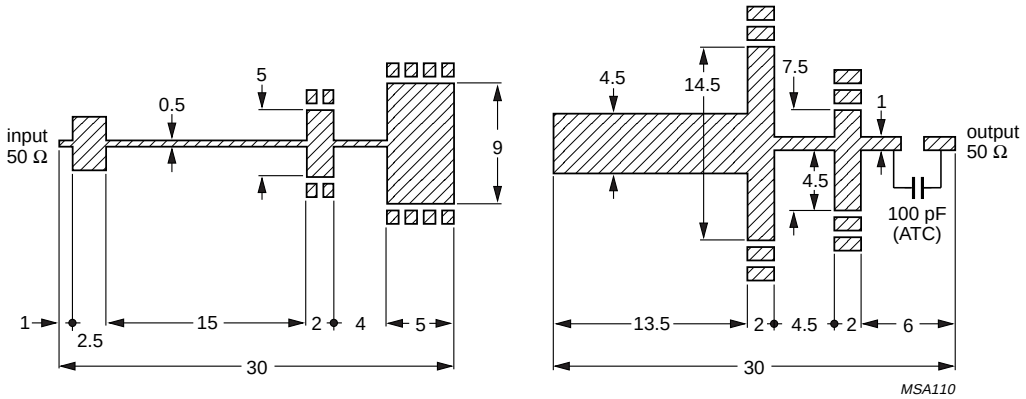
T_{mb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
I_{CBO}	collector cut-off current	V_{CB} = 40 V; I_E = 0	5	mA
		V_{CB} = 30 V; I_E = 0	2.5	mA
I_{CES}	collector cut-off current	V_{CE} = 35 V; R_{BE} = 0	25	mA
I_{EBO}	emitter cut-off current	V_{EB} = 1.5 V; I_C = 0	100	μA

APPLICATION INFORMATION

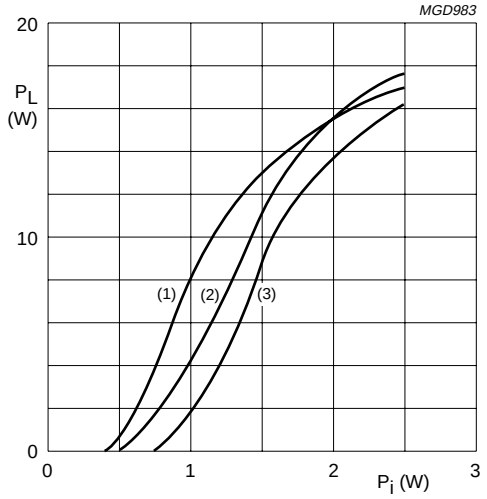
Microwave performance up to T_{mb} = 25 °C in a common base class B wideband amplifier.

MODE OF OPERATION	f (GHz)	V_{CC} (V)	P_L (W)	G_p (dB)	η_C (%)	Z_i; Z_L (Ω)
Class-B	1.4 to 1.8	28	≥12.5 typ. 15	≥7 typ. 7.8	≥38 typ. 45	see Figs 6 and 7



Dimensions in mm.
Substrate: Epsilam printed circuit board.
Thickness: 0.635 mm.
Permittivity: ε_r = 10.

Fig.3 Wideband test circuit board for 1.4 to 1.8 GHz operation.



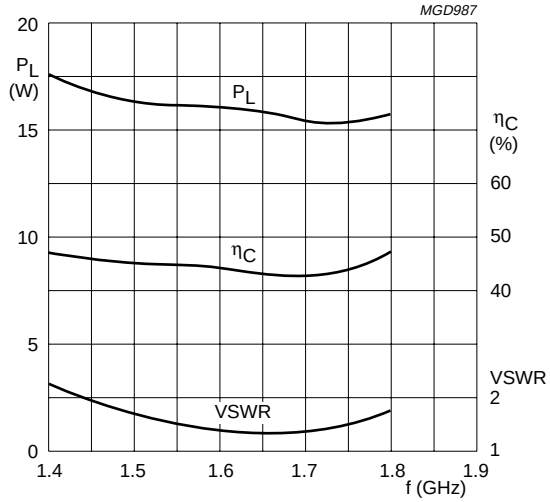
Class-B operation; V_{CC} = 28 V; T_{mb} = 25 °C.

(1) 1.6 GHz.

(2) 1.4 GHz.

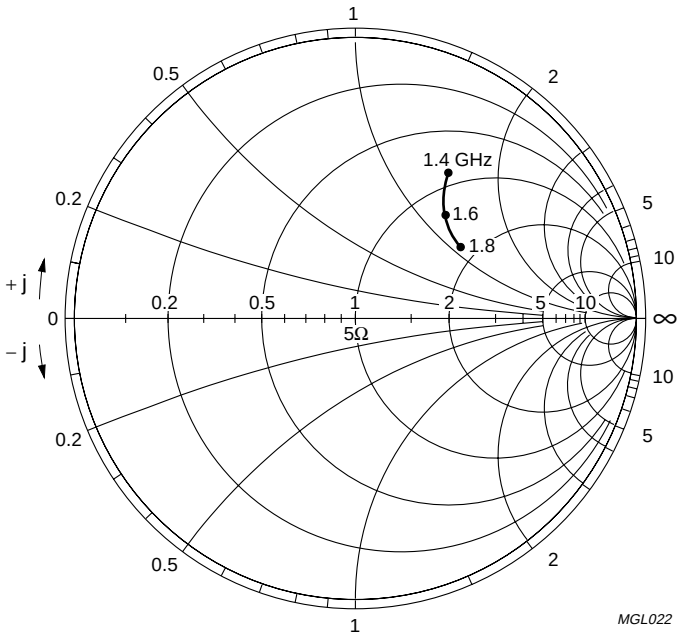
(3) 1.8 GHz.

Fig.4 Load power as a function of input power; typical values.



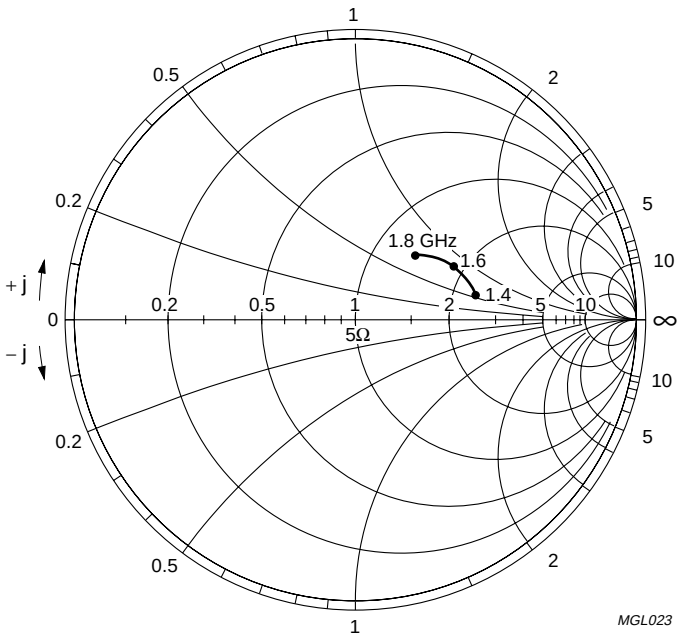
Class-B operation; V_{CC} = 28 V; T_{mb} = 25 °C; P_i = 2.5 W.

Fig.5 Load power, efficiency and VSWR as functions of frequency; typical values.



Z_o = 5 Ω.

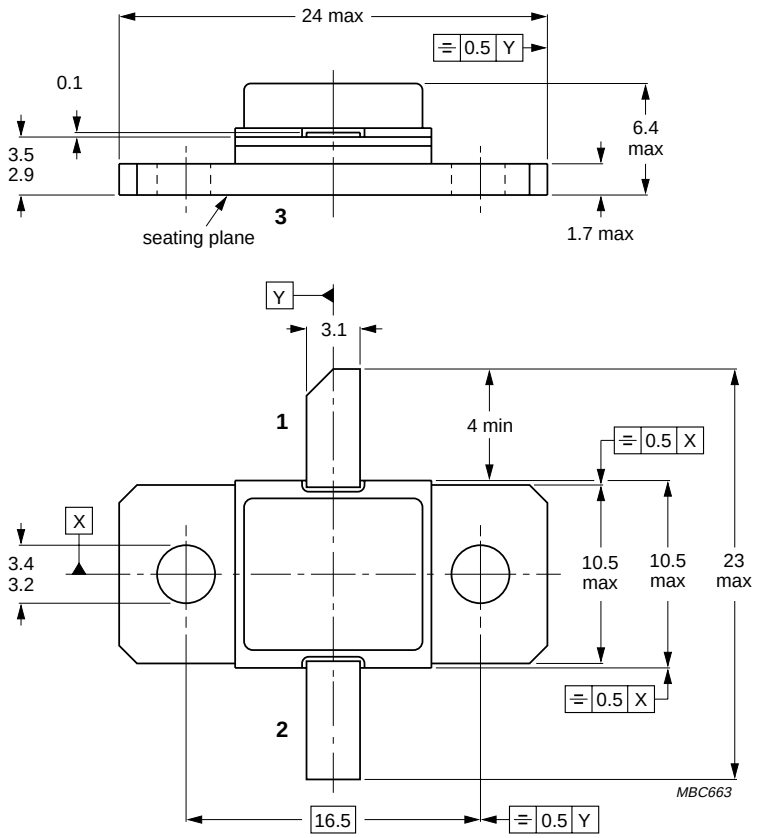
Fig.6 Input impedance as a function of frequency; typical values.



Z_o = 5 Ω.

Fig.7 Optimum load impedance as a function of frequency; typical values.

PACKAGE OUTLINE



Dimensions in mm.
Torque on screw: Max. 0.5 Nm.
Recommended screw: M3.

Fig.8 SOT443A.

DEFINITIONS

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

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Printed in The Netherlands 127147/00/02/pp12 Date of release: 1997 Feb 19 Document order number: 9397 750 01709

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